Product Change Notification / SYST-19BVSK770

Date:

21-Dec-2022

Product Category:

Power MOSFET Drivers

PCN Type:

Document Change

Notification Subject:

Data Sheet - 1.5A High-Speed 30V MOSFET Drivers Data Sheet

Affected CPNs:

SYST-19BVSK770_Affected_CPN_12212022.pdf
SYST-19BVSK770_Affected_CPN_12212022.csv

Notification Text:

SYST-19BVSK770

Microchip has released a new Datasheet for the 1.5A High-Speed 30V MOSFET Drivers Data Sheet of devices. If you are using one of these devices please read the document located at 1.5A High-Speed 30V MOSFET Drivers Data Sheet.

Notification Status: Final

Description of Change: • Added AEC-Q100 Automotive Qualification to Features, General Description and examples in Product Identification System.
• Updated Section 5.0 “Packaging Information”.
• Made minor formatting changes throughout the document.

Impacts to Data Sheet: See above details.
Reason for Change: To Improve Productivity

Change Implementation Status: Complete

Date Document Changes Effective: 21 Dec 2022

NOTE: Please be advised that this is a change to the document only the product has not been changed.

Markings to Distinguish Revised from Unrevised Devices: N/A

Attachments:

1.5A High-Speed 30V MOSFET Drivers Data Sheet

Please contact your local Microchip sales office with questions or concerns regarding this notification.

Terms and Conditions:

If you wish to receive Microchip PCNs via email please register for our PCN email service at our PCN home page select register then fill in the required fields. You will find instructions about registering for Microchips PCN email service in the PCN FAQ section.

If you wish to change your PCN profile, including opt out, please go to the PCN home page select login and sign into your myMicrochip account. Select a profile option from the left navigation bar and make the applicable selections.

Affected Catalog Part Numbers (CPN)

TC4431COA
TC4431CPA
TC4431VOA
TC4431VPA
TC4431EOA
TC4431EPA
TC4431EOA713
TC4431COA713
TC4431VOA713
TC4432COA
TC4432CPA
TC4432VOA
TC4432VOA-VAO
TC4432VPA
TC4432EOA
TC4432EPA
TC4432EOA713
TC4432COA713
TC4432VOA713

TC4431/TC4432

1.5A High-Speed 30V MOSFET Drivers

Features

- Passes AEC-Q100 Automotive Reliability Testing
- High-Peak Output Current: 1.5A
- Wide Input Supply Operating Range:
  - 4.5V to 30V
- High Capacitive Load Drive Capability:
  - 1000 pF in 25 ns
- Short Delay Time: <78 ns (Typical)
- Low Supply Current:
  - With Logic '1' Input: 2.5 mA
  - With Logic '0' Input: 300 µA
- Low Output Impedance: 7Ω
- Latch-Up Protected: Will Withstand >300 mA Reverse Current
- Electrostatic Discharge (ESD) Protected: 4 kV

Applications

- Small Motor Drive
- Power MOSFET Driver
- Driving Bipolar Transistors

General Description

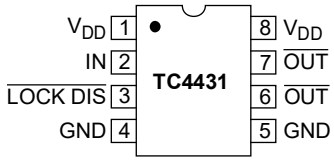
The TC4431/TC4432 are 30V CMOS buffers/drivers suitable for use in high-side driver applications. They do not latch up under any conditions within their power and voltage ratings. They can accept, without damage or logic upset, up to 300 mA of reverse current (of either polarity) being forced back into their outputs. All terminals are fully protected against electrostatic discharge up to 4 kV.

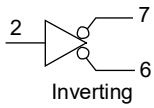
Undervoltage Lockout (UVLO) circuitry forces the output to a low state when the input supply voltage drops below 7V. For operation at lower voltages, disable the lockout and start-up circuit by grounding pin 3 ($\overline{\text{LOCK DIS}}$); for all other situations, pin 3 ($\overline{\text{LOCK DIS}}$) should be left floating. The undervoltage lockout and start-up circuit gives brown out protection when driving MOSFETs.

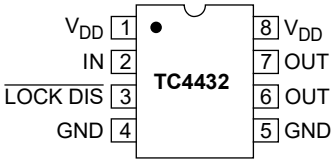
The TC4431 and TC4432 are AEC-Q100 qualified for automotive applications.

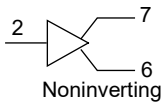
Package Type

8-Pin PDIP/SOIC/CERDIP



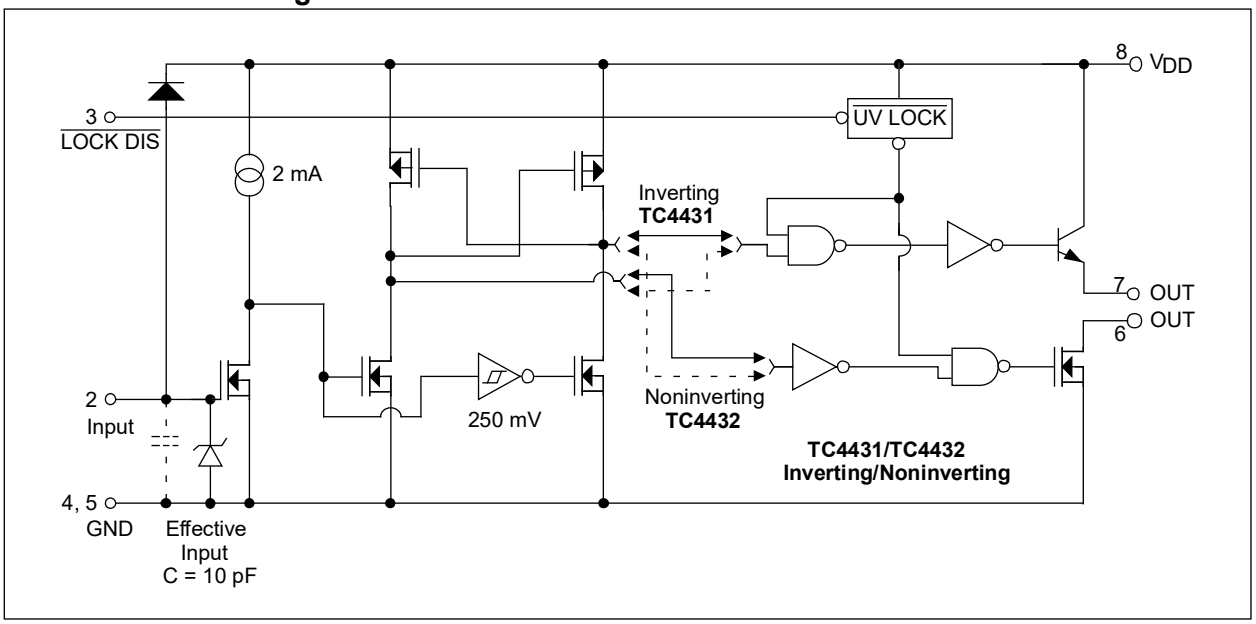






Note: SOIC pinout is identical to DIP. DIP is PDIP and CERDIP. This device could be connected together or separately; see Table 3-1 for pin information.

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Supply Voltage 36V

Input Voltage (**Note 1**)..... V_{DD} + 0.3V to GND

Package Power Dissipation ($T_A \leq 70°C$)

PDIP ..... 730 mW

CERDIP ..... 800 mW

SOIC ..... 470 mW

Maximum Junction Temperature (T_J)..... +150°C

Storage Temperature Range..... -65°C to +150°C

† Notice: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specification is not intended. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, T_A = +25ºC with 4.5V $\leq V_{DD} \leq$ 30V.

Parameter	Sym.	Min.	Typ.	Max.	Units	Conditions
Input						
Logic ‘1’, High Input Voltage	V_{IH}	2.4	—	—	V	
Logic ‘0’, Low Input Voltage	V_{IL}	—	—	0.8	V	
Input Current (**Note 1**)	I_{IN}	-1	—	1	µA	$0V \leq V_{IN} \leq 12V$
Output						
High Output Voltage	V_{OH}	V_{DD}-1.0	V_{DD}-0.8	—	V	I_{OUT} = 100 mA
Low Output Voltage	V_{OL}	—	—	0.025	V	
Output Resistance	R_O	—	7	10	Ω	I_{OUT} = 10 mA, V_{DD} = 30V
Peak Output Current	I_{PK}	— —	3.0 1.5	— —	A	Source: V_{DD} = 30V Sink: V_{DD} = 30V
Latch-Up Protection Withstand Reverse Current	I_{REV}	—	0.3	—	A	Duty cycle $\leq$ 2%, t $\leq$ 300 µs
Switching Time (Note 2)						
Rise Time	t_R	—	25	40	ns	**Figure 4-1**
Fall Time	t_F	—	33	50	ns	**Figure 4-1**
Delay Time	t_{D1}	—	62	80	ns	**Figure 4-1**
Delay Time	t_{D2}	—	78	90	ns	**Figure 4-1**
Power Supply						
Power Supply Current	I_S	— —	2.5 0.3	4 0.4	mA	V_{IN} = 3V V_{IN} = 0V
Start-Up Threshold	V_S	—	8.4	10	V	
Drop-Out Threshold	V_{DO}	7	7.7	—	V	**Note 3**

Note 1: For inputs >12V, add a 1 kΩ resistor in series with the input. See **Section 2.0 “Typical Performance Curves”** for input current graph.

2: Switching times are ensured by design.

3: For operation below 7V, pin 3 ($\overline{\text{LOCK DIS}}$) should be tied to ground to disable the lockout and start-up circuit; otherwise, pin 3 must be left floating.

DC CHARACTERISTICS (OVER OPERATING TEMPERATURE RANGE)

Electrical Specifications: Unless otherwise noted, over operating temperature range with 4.5V ≤ V_{DD} ≤ 30V.

Parameter	Sym.	Min.	Typ.	Max.	Units	Conditions
Input						
Logic '1', High Input Voltage	V_{IH}	2.4	—	—	V	
Logic '0', Low Input Voltage	V_{IL}	—	—	0.8	V	
Input Current (Note 1)	I_{IN}	-10	—	10	µA	0V ≤ V_{IN} ≤ 12V
Output						
High Output Voltage	V_{OH}	V_{DD}-1.2	—	—	V	I_{OUT} = 100 mA
Low Output Voltage	V_{OL}	—	—	0.025	V	
Output Resistance	R_O	—	—	12	Ω	I_{OUT} = 10 mA, V_{DD} = 30V
Switching Time (Note 2)						
Rise Time	t_R	—	—	60	ns	Figure 4-1
Fall Time	t_F	—	—	70	ns	Figure 4-1
Delay Time	t_{D1}	—	—	100	ns	Figure 4-1
Delay Time	t_{D2}	—	—	110	ns	Figure 4-1
Power Supply						
Power Supply Current	I_S	— —	— —	6 0.7	mA	V_{IN} = 3V V_{IN} = 0V
Start-Up Threshold	V_S	—	8.4	10	V	
Drop-Out Threshold	V_{DO}	7	7.7	—	V	Note 3

Note 1: For inputs >12V, add a 1 kΩ resistor in series with the input. See **Section 2.0 "Typical Performance Curves"** for input current graph.

2: Switching times are ensured by design.

3: For operation below 7V, pin 3 ($\overline{\text{LOCK DIS}}$) should be tied to ground to disable the lockout and start-up circuit; otherwise, pin 3 must be left floating.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all parameters apply with 4.5V ≤ V_{DD} ≤ 30V.

Parameter	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Specified Temperature Range (C)	T_A	0	—	+70	ºC	
Specified Temperature Range (E)	T_A	-40	—	+85	ºC	
Specified Temperature Range (V)	T_A	-40	—	+125	ºC	
Maximum Junction Temperature	T_J	—	—	+150	ºC	
Storage Temperature Range	T_A	-65	—	+150	ºC	
Package Thermal Resistances:						
Thermal Resistance, 8L-SOIC	θ_{JA}	—	155	—	ºC/W	
Thermal Resistance, 8L-PDIP	θ_{JA}	—	125	—	ºC/W	
Thermal Resistance, 8L-CERDIP	θ_{JA}	—	150	—	ºC/W	

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, T_A = +25ºC with 4.5V ≤ V_{DD} ≤ 30V.

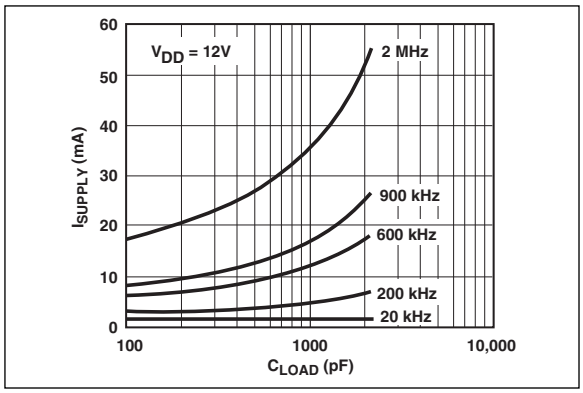


FIGURE 2-1: *Supply Current vs. Capacitive Load.*

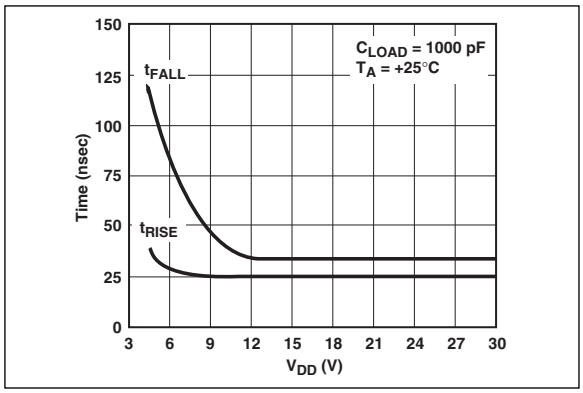


FIGURE 2-3: *Rise/Fall Time vs. V_{DD}.*

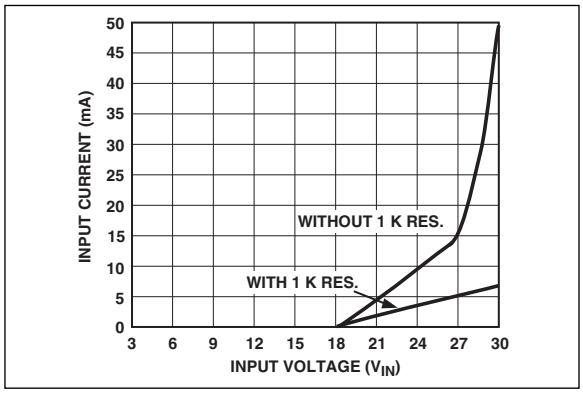


FIGURE 2-2: *Input Current vs. Input Voltage.*

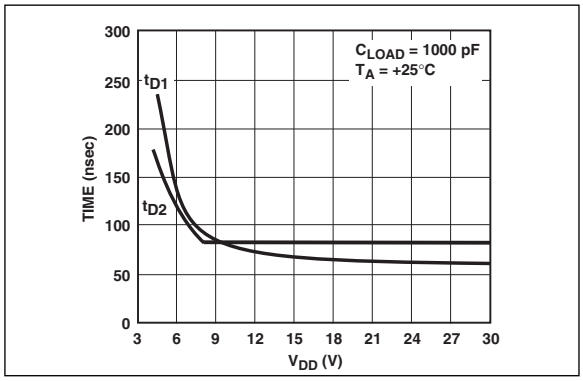


FIGURE 2-4: *t_{D1} and t_{D2} Delay vs. V_{DD}.*

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: Pin Function Table

Pin No.	Symbol	Description
1	V_{DD}	Supply Input, 4.5V to 30V
2	IN	TTL/CMOS Compatible Input
3	$\overline{\text{LOCK DIS}}$	Input Pin, Enable/Disable for UVLO
4	GND	Ground
5	GND	Ground
6	OUT	Drive Output, Pull Down
7	OUT	Drive Output, Pull Up
8	V_{DD}	Supply Input, 4.5V to 30V

3.1 Supply Input (V_{DD})

The V_{DD} input is the bias supply input for the MOSFET driver and is rated for 4.5V to 30V with respect to the ground pins. The V_{DD} input should be bypassed to ground with a local ceramic capacitor. The value of this capacitor should be chosen based on the capacitive load that is being driven.

3.2 Control Input (IN)

The MOSFET driver input is a TTL/CMOS compatible input with 250 mV of hysteresis between the high and low threshold voltages. If an input signal level of greater than 12V is applied to the device, a series current limiting resistor is recommended.

3.3 Lockout Disable ($\overline{\text{LOCK DIS}}$)

The lockout pin enables/disables the undervoltage lockout feature of the device. If undervoltage lockout is desired (output is not enabled until the bias voltage reaches 8.4V (typical) on the rising edge and is disabled when the bias voltage reaches 7.7V (typical) on the falling edge), the lockout pin should be left floating. If operation below 7V is desired, the lockout pin should be tied to ground.

3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high-peak currents which discharge the load capacitor. Both ground pins should be used to ensure proper operation. The ground pins should be tied into a ground plane or have short traces to the bias supply source return.

3.5 Drive Output (OUT)

The TC4431/TC4432 devices have individual source and sink output pins. This feature can be used to adjust the rise and fall time independently by adding separate charge and discharge resistors external to the device. Pin 7 (source output) can source 3A peak currents into capacitive loads and pin 6 (sink output) can sink 1.5A peak currents from a capacitive load.

4.0 APPLICATION INFORMATION

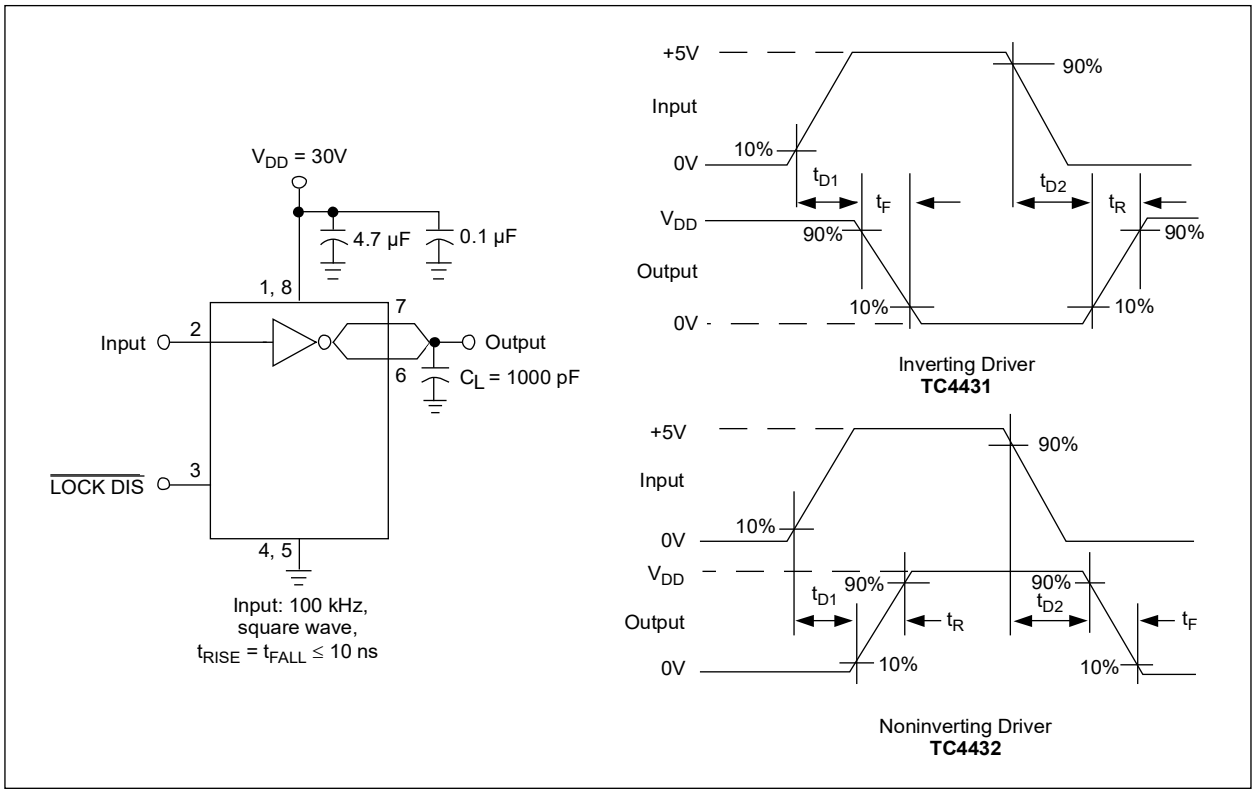
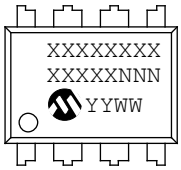


FIGURE 4-1: *Switching Time Test Circuit.*

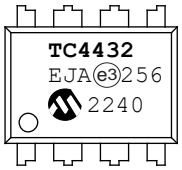
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

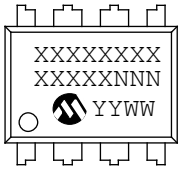
8-Lead CERDIP (300 mil)



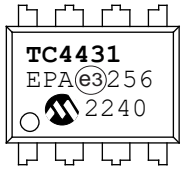
Example:



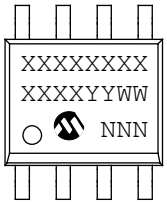
8-Lead PDIP (300 mil)



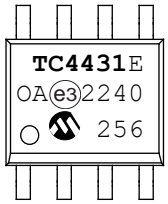
Example:



8-Lead SOIC (150 mil)



Example:

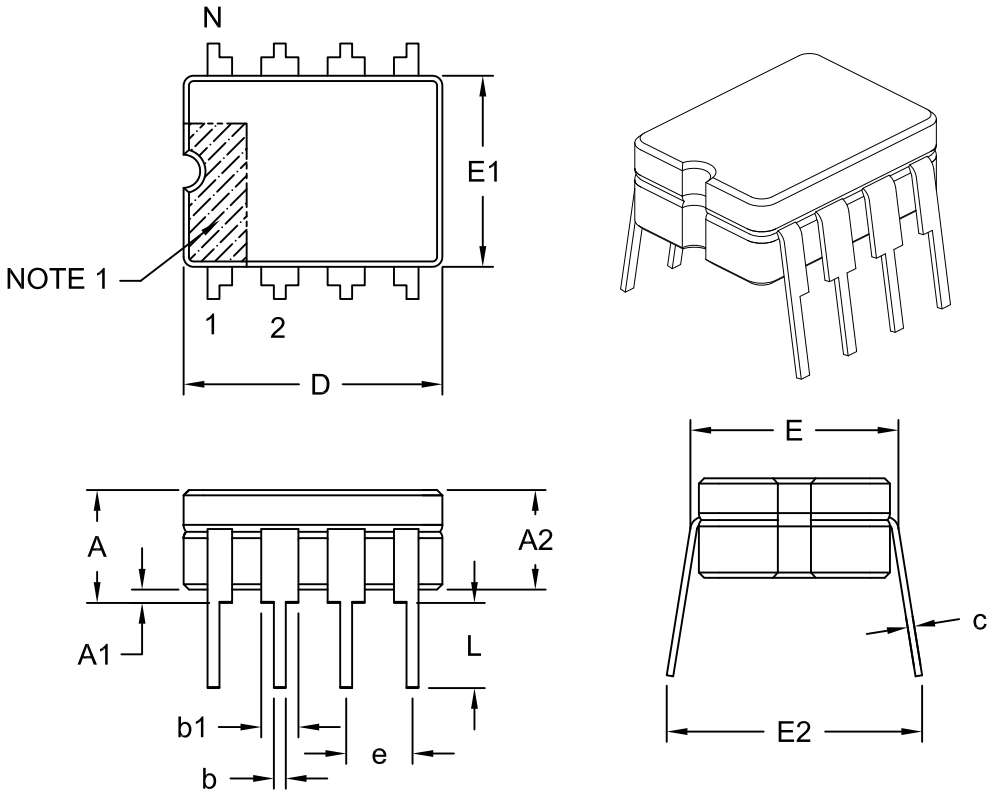


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

8-Lead Ceramic Dual In-Line (JA) ~ .300" Body [CERDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		.100 BSC	
Top to Seating Plane	A	-	-	.200
Base to Seating Plane §	A1	.015	-	-
Ceramic Package Height	A2	.140	-	.175
Shoulder to Shoulder Width	E	.290	-	.320
Ceramic Pkg. Width	E1	.230	.248	.300
Overall Length	D	.370	.380	.400
Tip to Seating Plane	L	.125	-	.200
Lead Thickness	c	.008	-	.015
Upper Lead Width	b1	.045	-	.065
Lower Lead Width	b	.015	-	.023
Overall Row Spacing	E2	.314	-	.410

Notes:

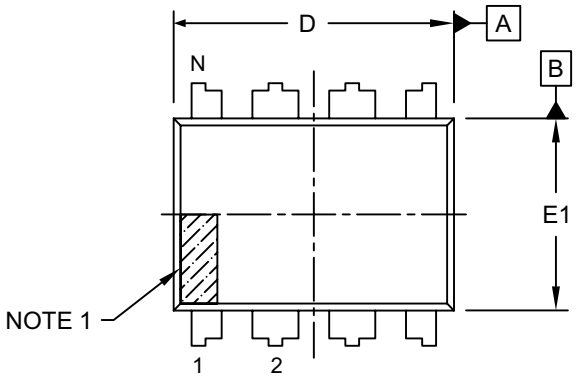
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

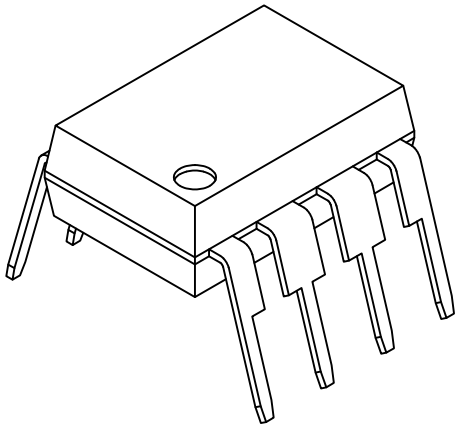
Microchip Technology Drawing No. C04-001C

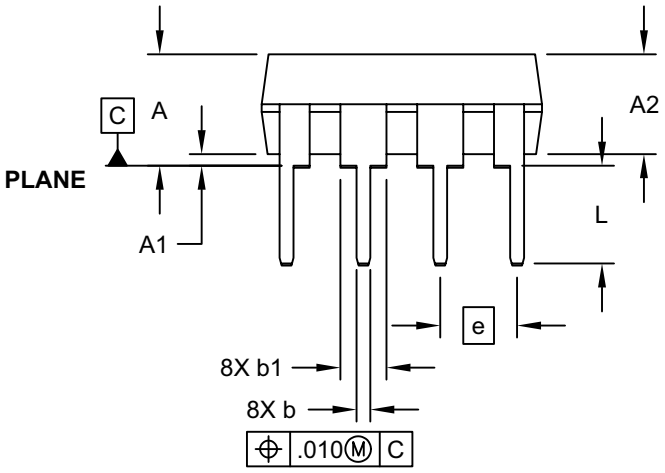
8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

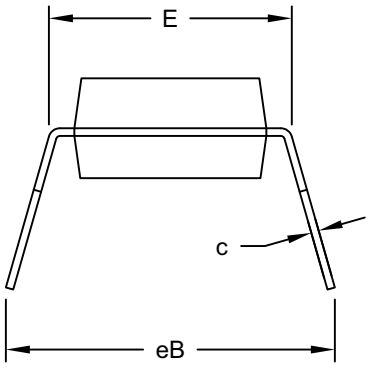


TOP VIEW





SIDE VIEW

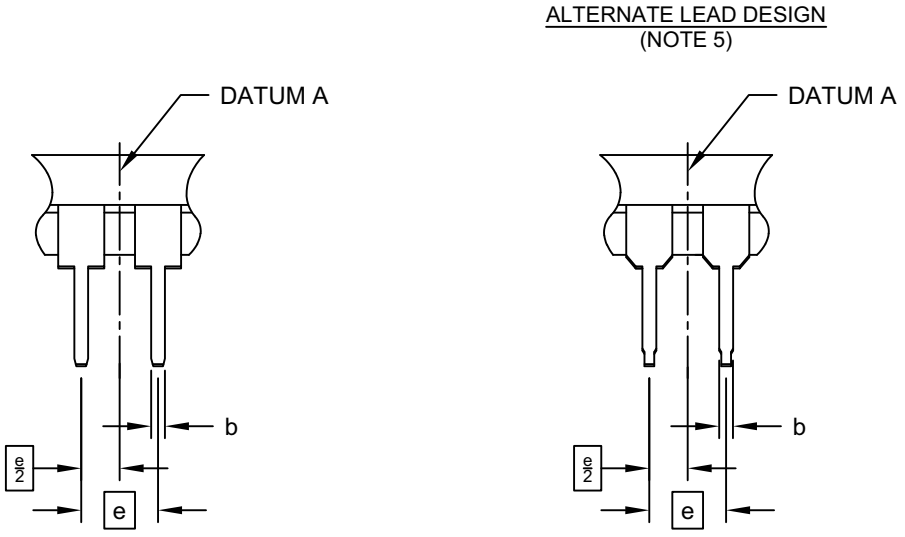


END VIEW

Microchip Technology Drawing No. C04-018-P Rev F Sheet 1 of 2

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		.100 BSC	
Top to Seating Plane	A	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	-	-	.430

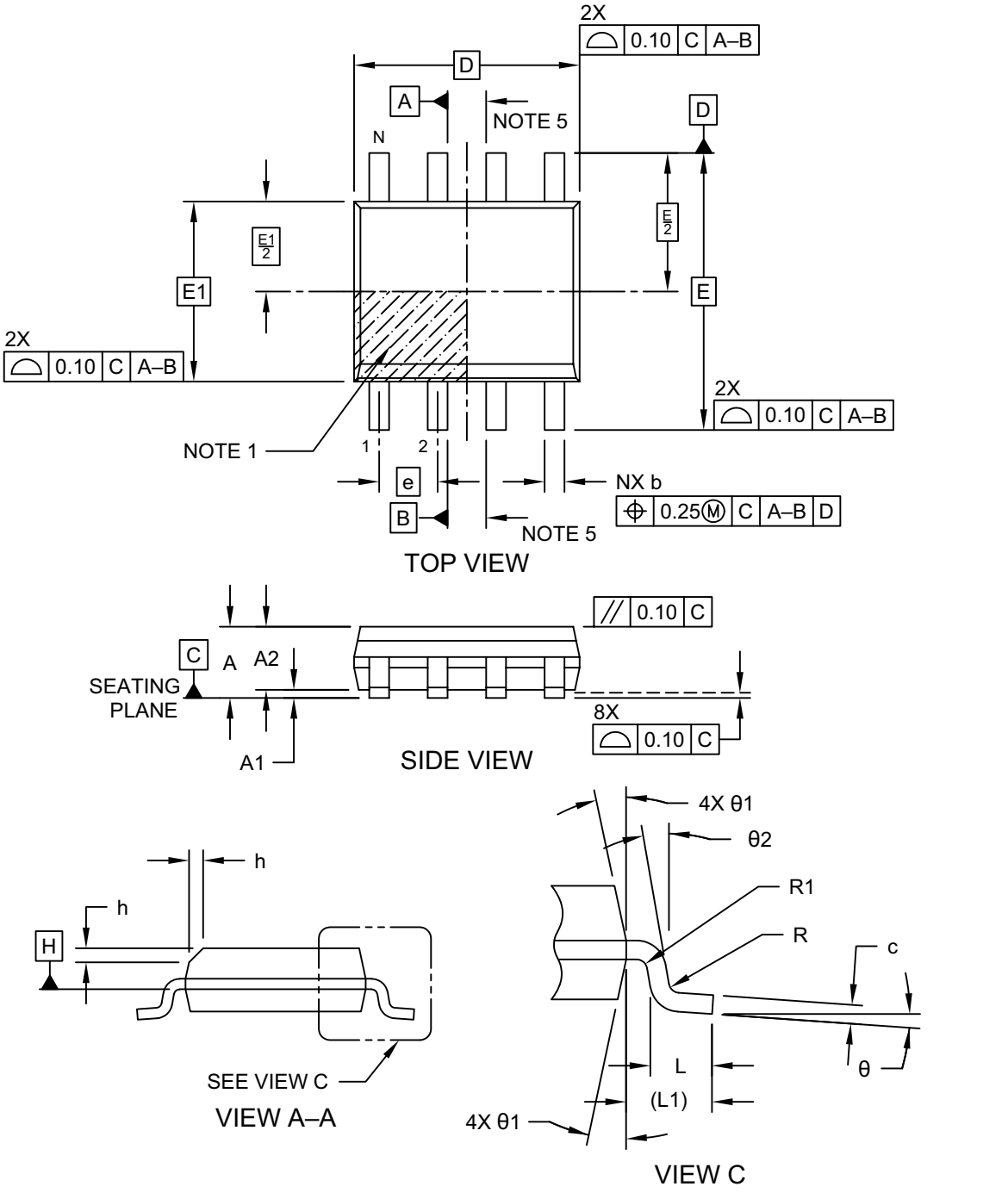
Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
5. Lead design above seating plane may vary, based on assembly vendor.

Microchip Technology Drawing No. C04-018-P Rev F Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

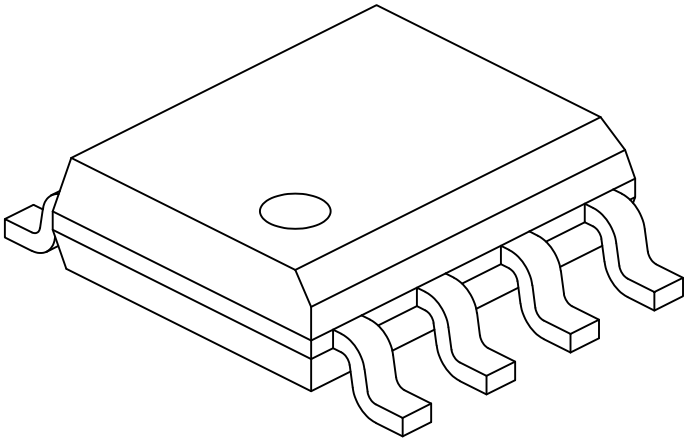
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057-SN Rev K Sheet 1 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		1.27 BSC	
Overall Height	A	–	–	1.75
Molded Package Thickness	A2	1.25	–	-
Standoff §	A1	0.10	–	0.25
Overall Width	E		6.00 BSC	
Molded Package Width	E1		3.90 BSC	
Overall Length	D		4.90 BSC	
Chamfer (Optional)	h	0.25	–	0.50
Foot Length	L	0.40	–	1.27
Footprint	L1		1.04 REF	
Lead Thickness	c	0.17	–	0.25
Lead Width	b	0.31	–	0.51
Lead Bend Radius	R	0.07	–	–
Lead Bend Radius	R1	0.07	–	–
Foot Angle	θ	0°	–	8°
Mold Draft Angle	θ1	5°	–	15°
Lead Angle	θ2	0°	–	–

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
4. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.
5. Datums A & B to be determined at Datum H.

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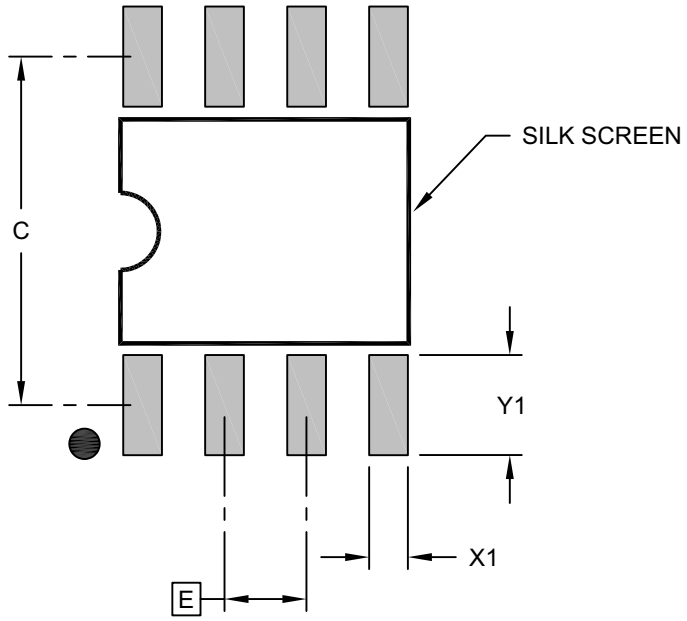
8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	C		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev K

APPENDIX A: REVISION HISTORY

Revision E (December 2022)

The following is the list of modifications:

- Added AEC-Q100 Automotive Qualification to Features, General Description and examples in Product Identification System.
- Updated **Section 5.0 "Packaging Information"**.
- Made minor formating changes throughout the document.

Revision D (December 2007)

The following is the list of modifications:

- **Section 1.0 "Electrical Characteristics"**: Added V temperature information to Temperature Characteristics table.
- Added Revision History.
- Added V temperature range to Product identification System page.

Revision C (May 2003)

- Undocumented changes.

Revision B (May 2002)

- Undocumented changes.

Revision A (April 2002)

- Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	X	/XX	-XXX
Device	Temperature Range	Package	Qualification

Device:	TC4431:	1.5A High-Speed 30V MOSFET Driver, Inverting
	TC4432:	1.5A High-Speed 30V MOSFET Driver, Noninverting
Temperature Range:	C =	0°C to +70°C
	E =	-40°C to +85°C
	V =	-40°C to +125°C
Package:	JA =	Ceramic Dual In-line (300 mil Body), 8-lead *
	OA =	Plastic SOIC, (150 mil Body), 8-lead
	OA713 =	Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel)
	PA =	Plastic DIP (300 mil Body), 8-lead* *
Qualification:	Blank =	Standard Part
	VAO =	Automotive AEC-Q100 Qualified

* Offered in E-temp range only
* * The only package offered in the V temp range

*All currently available VAO variants are shown in the examples.
Contact your Local Microchip sales office to request automotive qualified variants for other package types

Examples:

a) TC4431COA: 1.5A MOSFET driver, SOIC package, 0°C to +70°C.
b) TC4431EJA: 1.5A MOSFET driver, CERDIP package, -40ºC to +85ºC.
c) TC4431VPA: 1.5A MOSFET driver, PDIP package, -40°C to +125°C.

a) TC4432CPA: 1.5A MOSFET driver, PDIP package, 0°C to +70°C.
b) TC4432EPA: 1.5A MOSFET driver, PDIP package, -40°C to +85°C.
c) TC4432VOA713: Tape and Reel, 1.5A MOSFET driver, SOIC package,-40°C to +125°C.
d) TC4432VOA-VAO: 1.5A MOSFET driver, PDIP package, Automotive Qualified

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